



## KPHBM-2012QBDSURKC 2.0 x 1.25 mm SMD Chip LED Lamp

### DESCRIPTIONS

- The Blue source color devices are made with InGaN Light Emitting Diode
- The Hyper Red source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- Electrostatic discharge and power surge could damage the LEDs
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- All devices, equipments and machineries must be electrically grounded

### FEATURES

- 2.0 mm x 1.25 mm SMD LED, 0.45 mm max. thickness
- Low power consumption
- Wide viewing angle
- Ideal for backlight and indicator
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- RoHS compliant

### APPLICATIONS

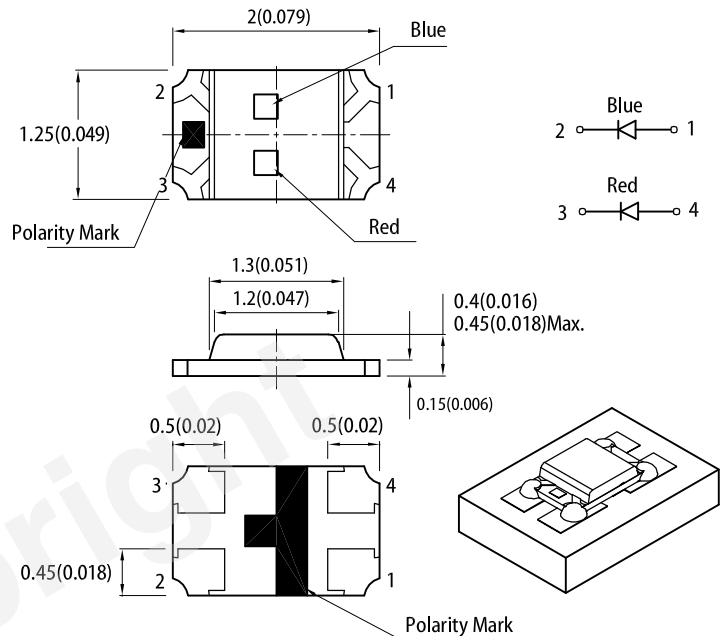
- Backlight
- Status indicator
- Home and smart appliances
- Wearable and portable devices
- Healthcare applications

### ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices

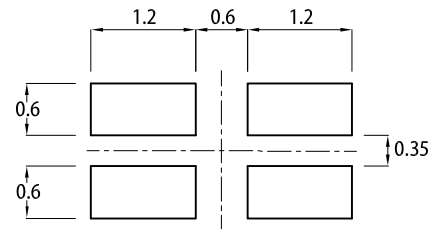


### PACKAGE DIMENSIONS



### RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.1(0.004") unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
4. The device has a single mounting surface. The device must be mounted according to the specifications.

### SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 20mA <sup>[2]</sup>		Viewing Angle <sup>[1]</sup>
			Min.	Typ.	2θ1/2
KPHBM-2012QBDSURKC	■ Blue (InGaN)	Water Clear	40	80	120°
			*40	*80	
	■ Hyper Red (AlGaInP)		120	250	
			*40	*80	

Notes:  
 1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.  
 2. Luminous intensity / luminous flux: +/-15%.  
 \* Luminous intensity value is traceable to CIE127-2007 standards.

**ELECTRICAL / OPTICAL CHARACTERISTICS at T<sub>A</sub>=25°C**

Parameter	Symbol	Emitting Color	Value		Unit
			Typ.	Max.	
Wavelength at Peak Emission I <sub>F</sub> = 20mA	λ <sub>peak</sub>	Blue Hyper Red	460 645	-	nm
Dominant Wavelength I <sub>F</sub> = 20mA	λ <sub>dom</sub> <sup>[1]</sup>	Blue Hyper Red	465 630	-	nm
Spectral Bandwidth at 50% Φ REL MAX I <sub>F</sub> = 20mA	Δλ	Blue Hyper Red	25 28	-	nm
Capacitance	C	Blue Hyper Red	100 35	-	pF
Forward Voltage I <sub>F</sub> = 20mA	V <sub>F</sub> <sup>[2]</sup>	Blue Hyper Red	3.3 1.95	4.0 2.5	V
Reverse Current (V <sub>R</sub> = 5V)	I <sub>R</sub>	Blue Hyper Red	-	50 10	uA

**Notes:**

1. The dominant wavelength (λ<sub>d</sub>) above is the setup value of the sorting machine. (Tolerance λ<sub>d</sub>: ±1nm.)
2. Forward voltage: ±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

**ABSOLUTE MAXIMUM RATINGS at T<sub>A</sub>=25°C**

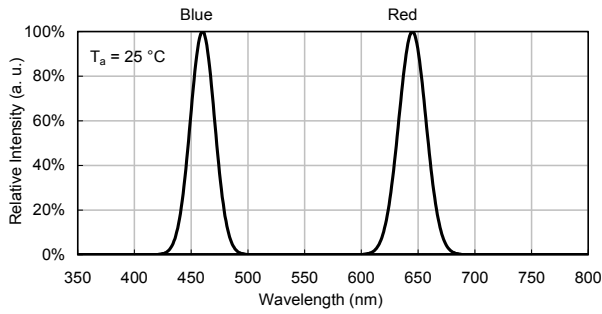
Parameter	Symbol	Value		Unit
		Blue	Hyper Red	
Power Dissipation	P <sub>D</sub>	120	75	mW
Reverse Voltage	V <sub>R</sub>	5	5	V
Junction Temperature	T <sub>j</sub>	115	115	°C
Operating Temperature	T <sub>op</sub>	-40 to +85		°C
Storage Temperature	T <sub>stg</sub>	-40 to +85		°C
DC Forward Current	I <sub>F</sub>	30	30	mA
Peak Forward Current	I <sub>FM</sub> <sup>[1]</sup>	150	185	mA
Electrostatic Discharge Threshold (HBM)	-	250	3000	V

**Notes:**

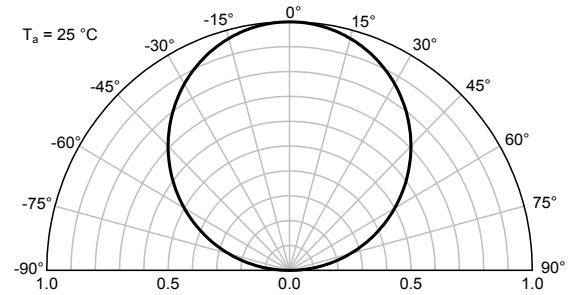
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

## TECHNICAL DATA

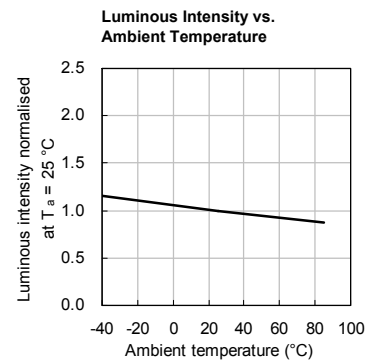
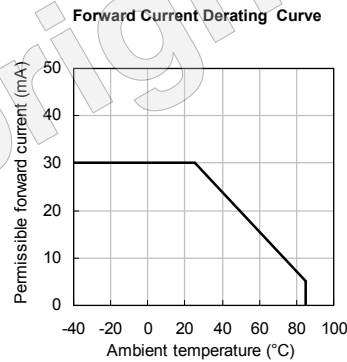
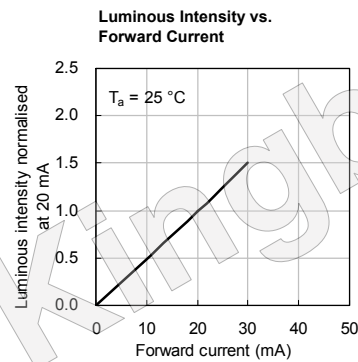
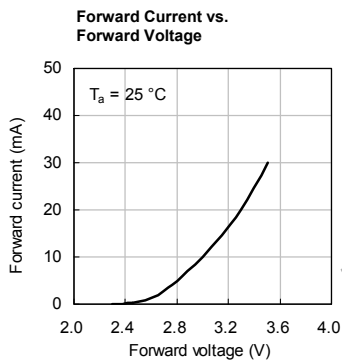
### RELATIVE INTENSITY vs. WAVELENGTH



### SPATIAL DISTRIBUTION



## BLUE



## HYPER RED

